



DDR3 Notebook SO-DIMM

Description

TwinMOS DDR3 SO-DIMM operates with a voltage of 1.35 and 1.5 volts to achieve both energy and electricity saving and meet environmental protection regulation. Moreover, TwinMOS DDR3 SO-DIMM provides various frequency and capacity selections to meet different levels of requirements of consumers in use. DDR3 from TwinMOS is characterized by its high speed, low power consumption, and high efficiency features. More importantly, it is compatible with various motherboards using various Notebooks on the market.

Specification

Module Type	DDR3 SO-DIMM for Notebook	
Capacity	2GB / 4GB / 8GB	
Frequency	1333MHz	1600Mhz
Data Transfer	10,664MB/s	12,800MB/s
Bandwidth	(PC3 10600)	(PC3 12,800)
Latency	CL9-9-9-24	CL11-11-11-28
Voltage	1.5V / 1.35V	
Dimensions	30(H) x 67.6(L) mm	
Warranty	Product Lifetime Warranty	

Ordering Information

Frequency	CAS Latency/Voltage	Capacity	IC Specifications	Part Number	EAN
DDR3 - 1333 PC3-10600	CL9-9-9-24 1.5V	2GB	x8	MDD32GB1333N	6291104600713
		4GB	x8	MDD34GB1333N	6291104601550
		8GB	x8	MDD38GB1333N	6291104602861
DDR3 - 1600 PC3-12800	CL11-11-11-28 1.5V	2GB	x8	MDD32GB1600N	6291104604414
		4GB	x8	MDD34GB1600N	6291104604421
		8GB	x8	MDD38GB1600N	6291104603950

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